

isc N-Channel MOSFET Transistor

IRF1324, IIRF1324

• FEATURES

- Static drain-source on-resistance:
 R_{DS}(on) ≤1.5mΩ
- Enhancement mode:
- · Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

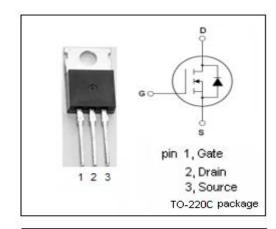
• reliable device for use in a wide variety of applications

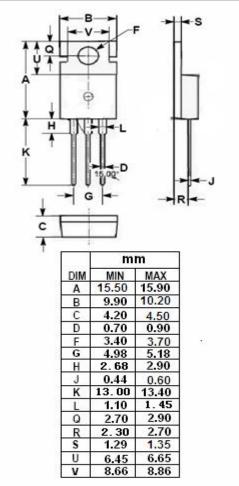
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	24	V
V _{GS}	Gate-Source Voltage	±20	V
I _D	Drain Current-Continuous	195	А
I _{DM}	Drain Current-Single Pulsed	1412	А
P _D	Total Dissipation @T _C =25°C	300	W
Tj	Max. Operating Junction Temperature	175	${\mathbb C}$
T _{stg}	Storage Temperature	-55~175	${\mathbb C}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.50	°C/W
Rth(ch-a)	Channel-to-ambient thermal resistance	62	°C/W







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 250μA	24			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =250 μ A	2.0		4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =195A			1.5	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} =± 20V			±0.2	μ А
I _{DSS}	Drain-Source Leakage Current	V _{DS} =24V; V _{GS} = 0V			20	μ А
V _{SD}	Diode forward voltage	Is =195A, V _{GS} = 0 V			1.3	V

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